TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7WZ08FU,TC7WZ08FK

Dual 2 Input AND Gate

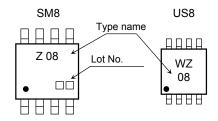
Features

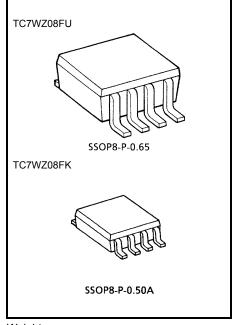
- High output drive: ±24 mA (min) at V_{CC} = 3 V
- Super high speed operation: t_{pd} = 2.5 ns (typ.)

at $V_{CC} = 5 \text{ V}, 50 \text{ pF}$

- Operation voltage range: V_{CC (opr)} = 1.65~5.5 V
- 5.5-V Tolerant inputs
- 5.5-V Power down protection outputs
- Matches the performance of TC74LCX series when operated at 3.3-V V_{CC}

Marking





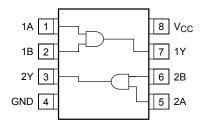
Weight

SSOP8-P-0.65 : 0.02 g (typ.) SSOP8-P-0.50A : 0.01 g (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Power supply voltage	Vcc	-0.5~6	V
DC input voltage	V _{IN}	-0.5~6	V
DC output voltage	V _{OUT}	-0.5~6	V
Input diode current	I _{IK}	-20	mA
Output diode current	I _{OK}	-20	mA
DC output current	lout	±50	mA
DC V _{CC} /ground current	I _{CC}	±50	mA
Power dissipation	P _D	300 (SM8) 200 (US8)	mW
Storage temperature	T _{stg}	-65~150	°C
Lead temperature (10s)	TL	260	°C

Pin Assignment (top view)





Truth Table

Α	В	Υ
L	L	L
L	Н	L
Н	L	L
Н	Н	Н

Logic Diagram



Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	Vcc	1.65~5.5	V
Supply voltage	VCC	1.5~5.5 (Note 1)	
Input voltage	V _{IN}	0~5.5	V
Output voltage	V _{OUT}	0~5.5 (Note 2)	V
		0~V _{CC} (Note 3)	
Operating temperature	T _{opr}	-40~85	°C
		$0~20~(V_{CC} = 1.8~V \pm 0.15~V, \ 2.5~V \pm 0.2~V)$	ns/V
Input rise and fall time	d _t /d _V	0~10 (V _{CC} = 3.3 V ± 0.3 V)	
		0~5 (V _{CC} = 5.5 V ± 0.5 V)	

Note 1: Data retention only

Note 2: $V_{CC} = 0 V$

Note 3: High or low state



Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Symbol Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
Cilarac	ienstics	Syllibol	Test	Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	OTHE
High level	V _{IH}			1.65~1.95	0.75 × V _{CC}	ı	_	0.75 × V _{CC}	-	- v	
	VIH			2.3~5.5	0.7 × V _{CC}	_	_	0.7 × V _{CC}	-		
voltage	Low level	V _{IL}	_		1.65~1.95		ı	0.25 × V _{CC}	ı	0.25 × V _{CC}	v
	Low level	VIL.			2.3~5.5			0.3 × V _{CC}		0.3 × V _{CC}	
					1.65	1.55	1.65	_	1.55	_	
				I _{OH} = -100 μA	2.3	2.2	2.3	_	2.2	_	
				10η – 100 μ/	3.0	2.9	3.0	_	2.9	_	
					4.5	4.4	4.5	_	4.4	_	
	High level	ligh level V _{OH}	$V_{IN} = V_{IH}$	$I_{OH} = -4 \text{ mA}$	1.65	1.29	1.52	_	1.29	_	
				$I_{OH} = -8 \text{ mA}$	2.3	1.9	2.15	_	1.9	_	
				$I_{OH} = -16 \text{ mA}$	3.0	2.4	2.8	_	2.4	_	
				$I_{OH} = -24 \text{ mA}$	3.0	2.3	2.68	_	2.3	_	
Output				$I_{OH} = -32 \text{ mA}$	4.5	3.8	4.2	_	3.8	_	
voltage		ow level V _{OL}	V _{IN} = I _O I _O I _O I _O	I _{OL} = 100 μA	1.65	_	0	0.1	_	0.1	
					2.3	_	0	0.1	_	0.1	
					3.0	_	0	0.1	_	0.1	
					4.5	_	0	0.1	_	0.1	
	Low level			I _{OL} = 4 mA	1.65	_	0.08	0.24	_	0.24	
				I _{OL} = 8 mA	2.3	_	0.1	0.3	_	0.3	
				I _{OL} = 16 mA	3.0	_	0.15	0.4	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.22	0.55	_	0.55	
				$I_{OL} = 32 \text{ mA}$	4.5	_	0.22	0.55	_	0.55	
Input leakage	Input leakage current I _{IN} V _{IN} = 5.5 V or GND		0~5.5	_		±1	_	±10	μА		
Power off leakage current I _{OFF} V _{IN} or V _{OUT} = 5.5 V		_{JT} = 5.5 V	0.0	_	_	1	_	10	μΑ		
Quiescent supply current		Icc	$V_{IN} = 5.5 \text{ V}$	or GND	1.65~5.5	_		1	_	10	μΑ

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AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3$ ns)

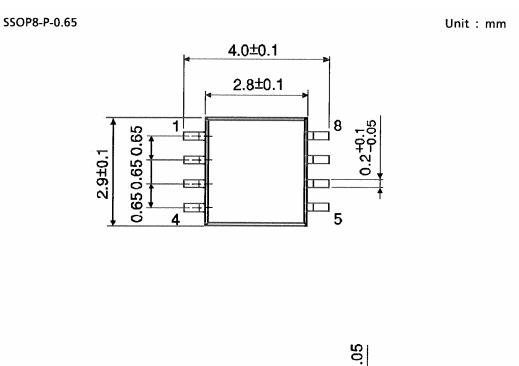
Characteristics	Symbol Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
Characteristics Sym		rest Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
Propagation delay time	t _{PLH}	C_L = 15 pF, R_L = 1 M Ω	1.8 ± 0.15	2.0	5.7	10.5	2.0	11.0	- ns
			2.5 ± 0.2	1.0	3.5	5.8	1.0	6.2	
			3.3 ± 0.3	0.8	2.6	3.9	0.8	4.3	
			5.0 ± 0.5	0.5	1.9	3.1	0.5	3.3	
		$C_L = 50$ pF, $R_L = 500 \Omega$	3.3 ± 0.3	1.2	3.2	4.8	1.2	5.2	
			5.0 ± 0.5	0.8	2.5	3.7	0.8	4.0	
Input capacitance	CIN	_	0~5.5	_	3.0	_	_	_	pF
Power dissipation capacitance	C _{PD} (Note 4)	(Note 4)	3.3	_	22		_	_	n.E
		5.5		37				- pF	

Note 4:CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$

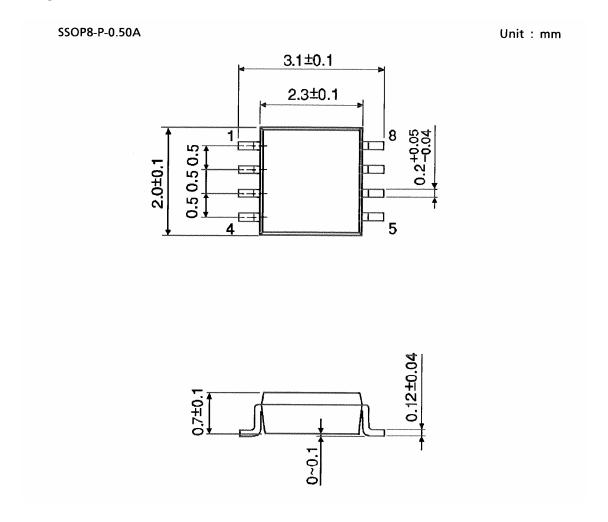
Package Dimensions



0~0.1

Weight: 0.02 g (typ.)

Package Dimensions



Weight: 0.01 g (typ.)

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